

NOT RECOMMENDED FOR NEW DESIGN USE DMN2058U



DMG3420U

N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _A = +25°C
20V	$29m\Omega$ @ $V_{GS} = 10V$	6.5A
	$35m\Omega$ @ $V_{GS} = 4.5V$	5.2A

Description

This new generation MOSFET has been designed to minimize the onstate resistance ($R_{DS(ON)}$) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

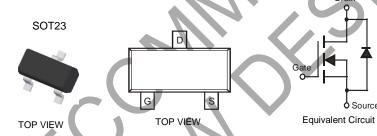
- · General Purpose Interfacing Switch
- Power Management Functions

Features

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208
- Terminals Connections: See Diagram Below
- Weight: 0.008 grams (Approximate)



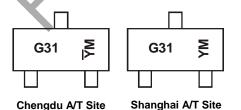
Ordering Information (Note 5)

Part Number	Qualification	Case	Packaging
DMG3420U-7	Standard	SOT23	3000/Tape & Reel
DMG3420UQ-7	Automotive	SOT23	3000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to https://www.diodes.com/quality/product-compliance-definitions/.
- 5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



G31 = Product Type Marking Code

YM = Date Code Marking for SAT (Shanghai Assembly/ Test site)

 $\overline{Y}M$ = Date Code Marking for CAT (Chengdu Assembly/ Test site)

 $Y \text{ or } \overline{Y} = Y \text{ ear (ex: } E = 2017)$

M = Month (ex: 9 = September)

Date Code Key

Date Code Key												
Year	2009	-	2017	2018	3 201	19 20	020 2	2021	2022	2023	2024	2025
Code	W	2	Е	F	G	;	Н		J	K	L	М
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



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Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characte	eristic		Symbol	Value	Unit
Drain-Source Voltage			V _{DSS}	20	V
Gate-Source Voltage		V _{GSS}	±12	V	
Continuous Drain Current (Note 6) Steady $T_A = +25^{\circ}C$ $T_A = +85^{\circ}C$			I _D	5.47 3.43	А
Pulsed Drain Current (Note 7)			I _{DM}	20	Α

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 6)	P _D	0.74	W
Thermal Resistance, Junction to Ambient @T _A = +25°C (Note 6)	R _{0JA}	167	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)						
Drain-Source Breakdown Voltage	BVDSS	20	_ <		V	$V_{GS} = 0V, I_D = 250\mu A$
Zero Gate Voltage Drain Current T _J = +25°C	I _{DSS}	7	700	1.0	μA	$V_{DS} = 20V, V_{GS} = 0V$
Gate-Source Leakage	I _{GSS}	_	<i>(</i> -	±100	nA	$V_{GS} = \pm 12V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 8)						
Gate Threshold Voltage	$V_{GS(TH)}$	0.5	0.95	1.2	V	$V_{DS} = V_{GS}$, $I_D = 250\mu A$
	1		21	29		V _{GS} = 10V, I _D = 6A
Static Drain-Source On-Resistance			25	35	0	$V_{GS} = 4.5V, I_D = 5A$
Static Drain-Source On-Resistance	R _{DS(ON)}		34	48	mΩ	$V_{GS} = 2.5V, I_D = 4A$
			65	91		$V_{GS} = 1.8V, I_D = 2A$
Forward Transfer Admittance	Y _{fs}	_	9	_	S	$V_{DS} = 5V, I_D = 3.8A$
Diode Forward Voltage	V _{SD}	_	0.75	1.0	V	V _{GS} = 0V, I _S = 1A
DYNAMIC CHARACTERISTICS (Note 9)						
Input Capacitance	C _{iss}	_	434.7	_	pF	
Output Capacitance	Coss	_	69.1	_	pF	$V_{DS} = 10V, V_{GS} = 0V,$ f = 1.0MHz
Reverse Transfer Capacitance	C _{rss}	_	61.2	_	pF	1 = 1.0WH12
Gate Resistance	R_g	_	1.53	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$
Total Gate Charge	Qg	_	5.4	_	nC	
Gate-Source Charge	Q_{gs}	_	0.9	_	nC	$V_{GS} = 4.5V, V_{DS} = 10V,$
Gate-Drain Charge	Q_{gd}	_	1.5	_	nC	$I_D = 6A$
Turn-On Delay Time	t _{D(ON)}	_	6.5	_	ns	
Turn-On Rise Time	t _R	_	8.3	_	ns	$V_{DD} = 10V, V_{GS} = 5V,$
Turn-Off Delay Time	t _{D(OFF)}	_	21.6	_	ns	$R_L = 1.7\Omega$, $R_g = 6\Omega$
Turn-Off Fall Time	t _F		5.3		ns	

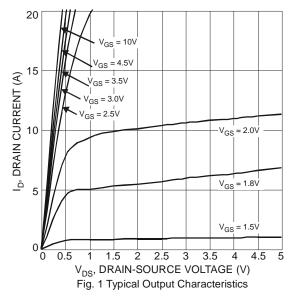
Notes:

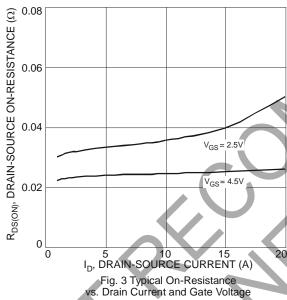
- 6. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

 7. Repetitive rating, pulse width limited by junction temperature.

 8. Short duration pulse test used to minimize self-heating effect.

 9. Guaranteed by design. Not subject to production testing.





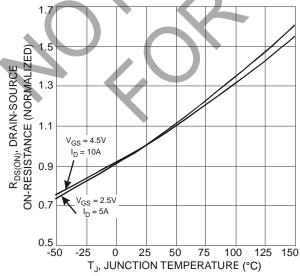
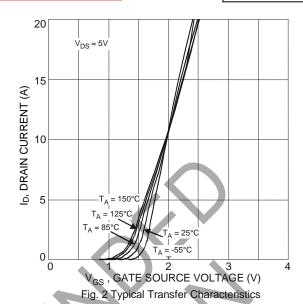


Fig. 5 On-Resistance Variation with Temperature



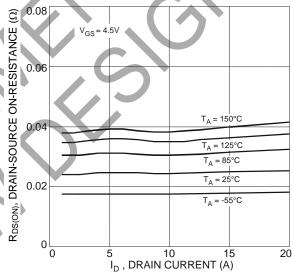


Fig. 4 Typical Drain-Source On-Resistance vs. Drain Current and Temperature

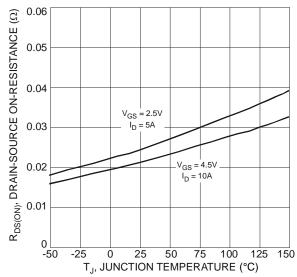


Fig. 6 On-Resistance Variation with Temperature







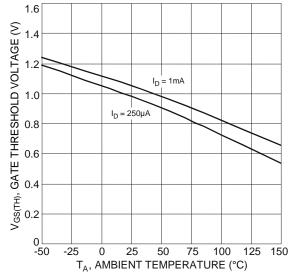
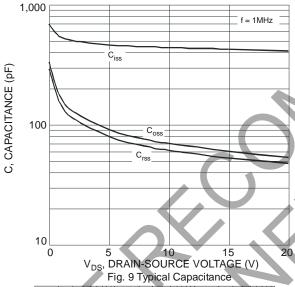
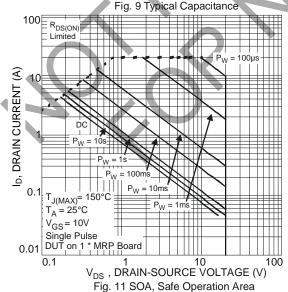
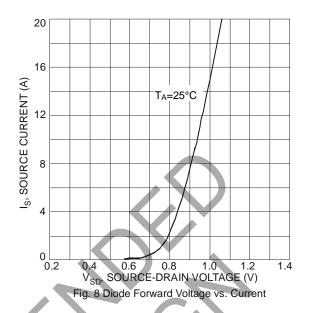


Fig. 7 Gate Threshold Variation vs. Ambient Temperature







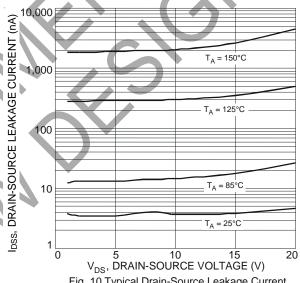
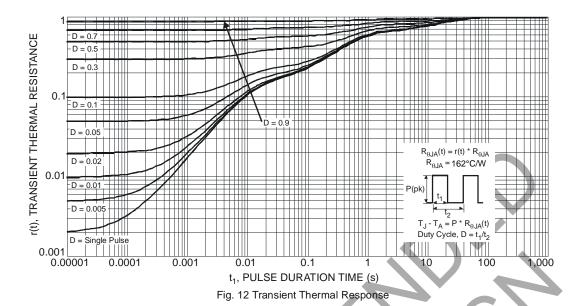
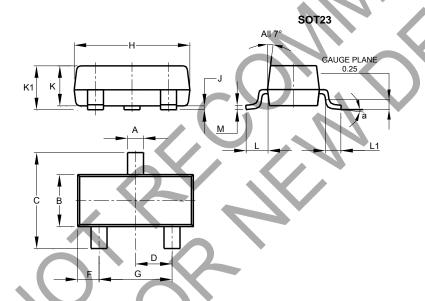


Fig. 10 Typical Drain-Source Leakage Current vs. Drain-Source Voltage



Package Outline Dimensions

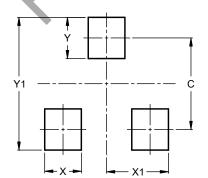
Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT23								
Dim	Min	Max	Тур					
Α	0.37	0.51	0.40					
В	1.20	1.40	1.30					
С	2.30	2.50	2.40					
D	0.89	1.03	0.915					
F	0.45	0.60	0.535					
G	1.78	2.05	1.83					
Н	2.80	3.00	2.90					
J	0.013	0.10	0.05					
K	0.890	1.00	0.975					
K1	0.903	1.10	1.025					
L	0.45	0.61	0.55					
L1	0.25	0.55	0.40					
М	0.085	0.150	0.110					
а	0°	8°						
All Dimensions in mm								

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version. SOT23



Dimensions	Value (in mm)
С	2.0
X	0.8
X1	1.35
Y	0.9
Y1	2.9



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